

**Product data sheet** 

#### **1. General description**

Planar passivated Silicon Controlled Rectifier (SCR) in a TO220F plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ( $T_{j(max)} = 150$  °C).

#### 2. Features and benefits

- High junction operating temperature capability (T<sub>i(max)</sub> = 150 °C)
- Good blocking voltage capability
- · High surge current capability
- Isolated mounting base package
- · Planar passivated for voltage ruggedness and reliability

#### 3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

#### 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>h</sub> ≤ 85 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	16	A
10111	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig 4; Fig 5	-	-	188	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	-	207	А
Tj	junction temperature		-	-	150	°C
Static ch	aracteristics	· · ·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	6	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V <sub>T</sub>	on-state voltage	$I_{T} = 16 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$	-	-	1.6	V
Dynamic	characteristics	· · ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	400	-	-	V/µs
	1		1			

### 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	А	anode		А Н К
3	G	gate		sym037
mb	n.c.	mounting base; isolated		
			$\left[ \begin{array}{c} 0 \end{array} \right]$	
			1 2 3	

### 6. Ordering information

Table 3.	Ordering	information
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Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
TYN16X-600CTF	TO220F	TYN16X-600CTFQ	Tube	50	SOT186A	14-Nov-2013		

## 7. Marking

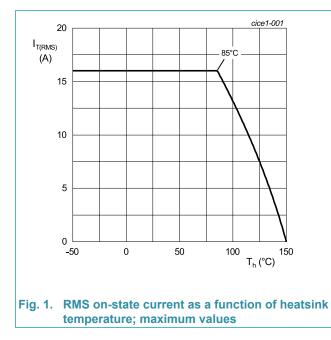
Table 4. Marking codes	
Type number	Marking codes
TYN16X-600CTF	TYN16X 600CTF

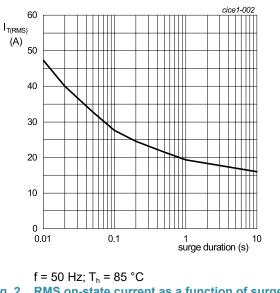
### 8. Limiting values

#### Table 5. Limiting values

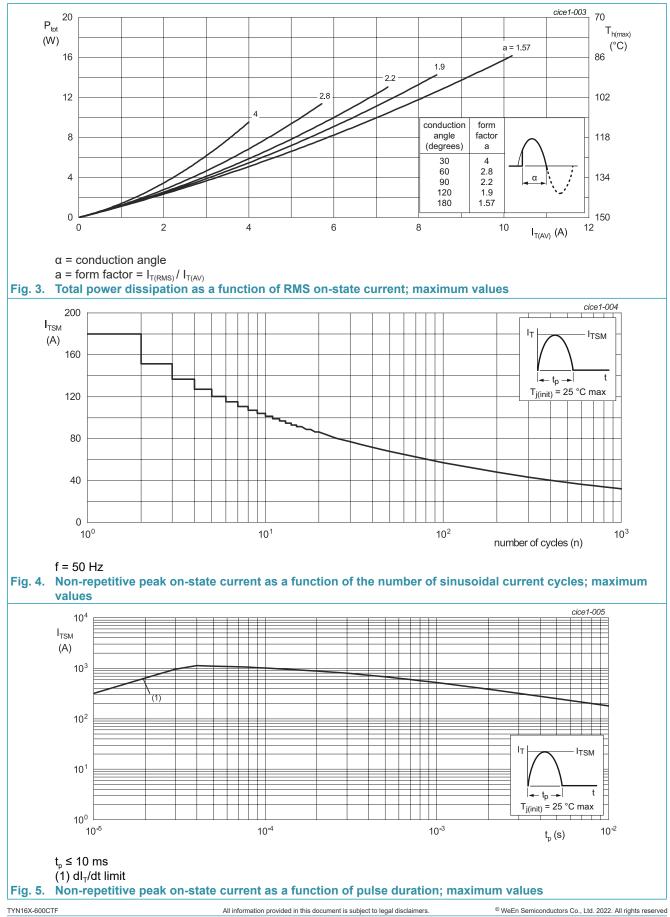
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	600	V
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>h</sub> ≤ 85 °C	-	10.2	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>h</sub> ≤ 85 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	16	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig 4; Fig 5	-	188	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	207	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	$t_p$ = 10 ms; sine-wave pulse	-	177	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 20 mA	-	100	A/µs
I <sub>GM</sub>	peak gate current		-	5	А
V <sub>GM</sub>	peak gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>i</sub>	junction temperature		-	150	°C



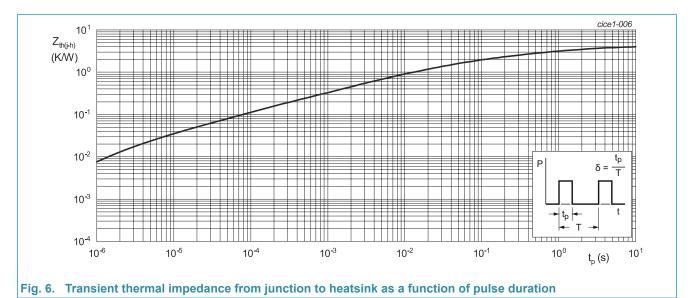






### 9. Thermal characteristics

Table 6. Th	ermal characteristics		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-h)</sub>		with heatsink compound; Fig 6	-	-	4	K/W
from junction to heatsink	-	without heatsink compound	-	-	5.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W



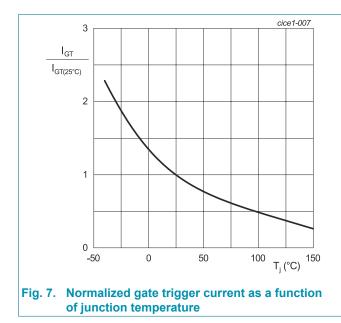
#### **10. Isolation characteristics**

#### Table 7. Isolation characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free		-	-	2500	V
C <sub>isol</sub>	isolation capacitance	f = 1 MHz; $T_h$ = 25 °C; from cathode to external heatsink		-	10	-	pF

### **11. Characteristics**

	haracteristics	Conditions	Min	Tun	Max	Unit
Symbol	Parameter	Conditions	Min	Тур	wax	Unit
Static cha	aracteristics		 			
I <sub>GT</sub>	gate trigger current	$V_{D}$ = 12 V; $I_{T}$ = 0.1 A; $T_{j}$ = 25 °C; <u>Fig. 7</u>	-	-	6	mA
I <sub>L</sub>	latching current	$V_{\rm D}$ = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	60	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 16 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	1.6	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A;T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.75	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A;T <sub>j</sub> = 150 °C	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	1	mA
I <sub>R</sub>	reverse current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	1	mA
Dynamic	characteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{\text{j}} = 150 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM}); exponential waveform; gate open circuit$	400	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM} = 16 \text{ A}; V_D = 600 \text{ V}; I_G = 100 \text{ mA};$ $(dI_G/dt)_M = 5 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$	-	2	-	μs
t <sub>q</sub>	commutated turn-off time	$I_{TM}$ = 2 A; t <sub>p</sub> = 50 µs; dV <sub>D</sub> /dt = 5 V/µs; dI/ dt = 30 A/µs	-	-	12	μs



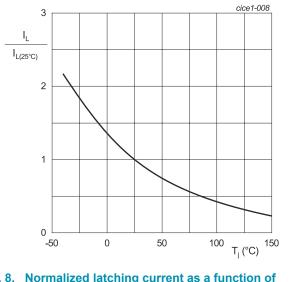
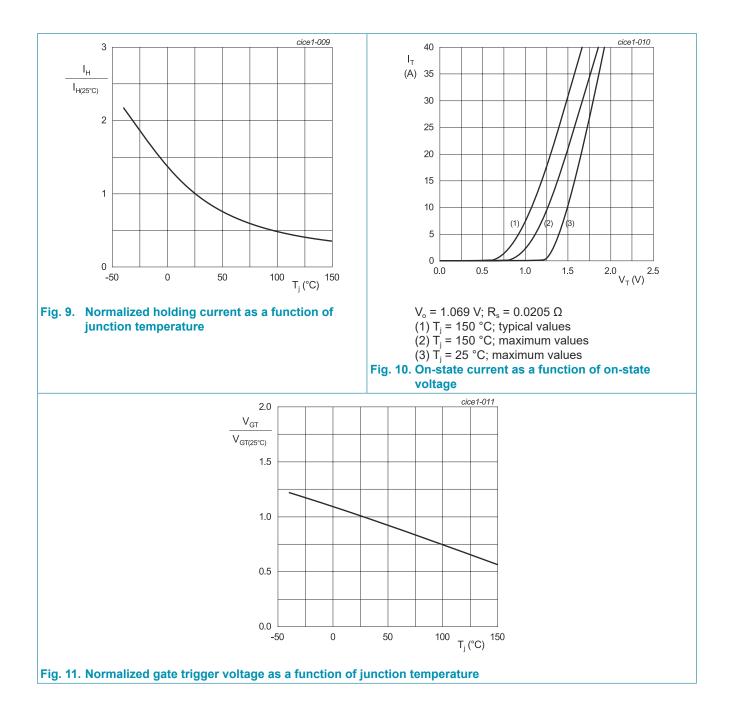


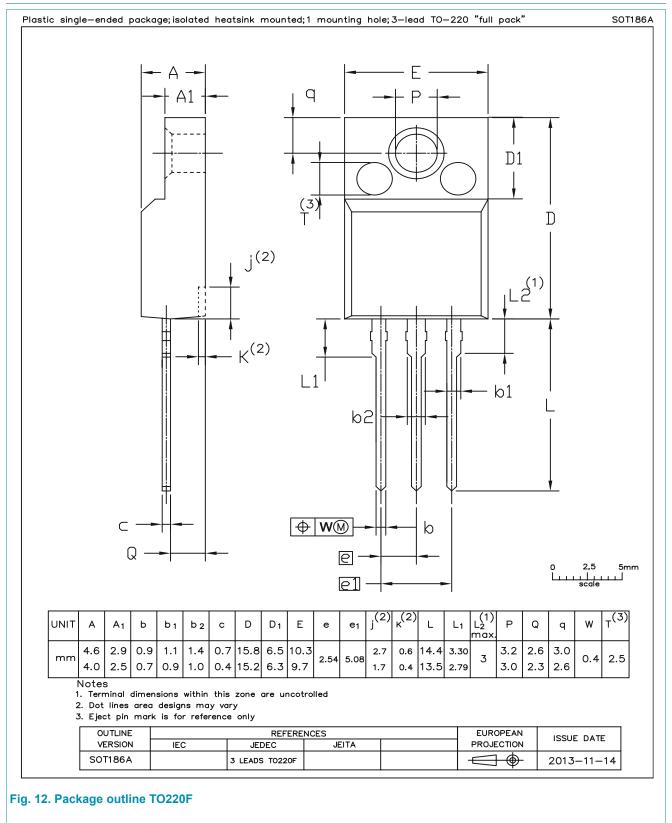
Fig. 8. Normalized latching current as a function of junction temperature

#### **WeEn Semiconductors**

TYN16X-600CTF



#### 12. Package outline



TYN16X-600CTF Product data sheet

### 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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# TYN16X-600CTF

#### 14. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	5
10. Isolation characteristics	5
11. Characteristics	6
12. Package outline	8
13. Legal information	9
14. Contents	

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